EAST Search History

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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S30	2	("6777677").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/10 16:30
S31	4700	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with root	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 16:36
S32	1117	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 16:37
S33	74038	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with root with size or location with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 16:38

S34	1	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with root with size with location with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 16:38
S35	2	"20050049836"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 16:39
S36	117	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 16:56
S37	2	("6888674").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/10 17:04
S38	119	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or inspect\$4) with (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 17:09

S39	1	\$3 or indicat\$3 or detect\$3 or identif\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR		2008/06/10 17:15
S40	17	\$3 or indicat\$3 or detect\$3 or identif\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OZ	2008/06/10 17:17
S41	1	or sens\$3) with (defect	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 17:17

S42	1	\$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10
S43	7	\$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10
S44	16	\$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 17:21

S45	5	\$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OS	2008/06/10
S46	5	\$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10

S47	4	\$3 or indicat\$3 or detect\$3 or identif\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10
S48	4	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$5) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (analyz\$3 or analys \$3 or diagnos\$3) with (mapping or match\$3) and compar\$4 with (predetermined or preset\$4 or predefined or reference or desired or expected or threshold or basic or histor\$6) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with pattern	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 17:25

S49		(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10
S50	114	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10
S51	2	("6777674").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/10 17:34
S52		(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10

		size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and ".mu.m"			mmmmmmmmm	mannam
S 53	0	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root and ".mu. m"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 17:40
S54	0	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root and ".mu. m"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10
S 55	1	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root and single with phase with particle	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10
S 56		(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root and phase with particle	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 17:43

S57	1213	702/117.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/10 18:12
S58	426	702/58.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 10:26
S59	5	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (adjust\$4 or correct\$4 or compensat\$4 or modif \$5 or calibrat\$4) with process\$3 with (die or semiconductor or wafer or chip or IC or integrated adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	O 0	2008/06/11
S60	111	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (adjust\$4 or correct \$4 or compensat\$4 or	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	S 0	2008/06/11

		modif\$5 or calibrat\$4) with process\$3 with (die or semiconductor or wafer or chip or IC or integrated adj circuit)		mmmmmmm.	annannannannannannannannannannannannann	munamunamunamunamunamunamunamunamunamuna
S61	6	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (adjust\$4 or correct \$4 or compensat\$4 or modif\$5 or calibrat\$4) with process\$3 with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (some semiconductor or wafer or chip or IC or integrated adj circuit) not \$59	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR		2008/06/11
S 62	0	\$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR		2008/06/11

S63		(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and focus with ion with beam	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 13:34
S64	8	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and focus\$3 with ion with beam	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 13:35
S65	0	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and focus\$3 with ion with beam same cross-section	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11

S66	0	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and ion with beam same cross-section	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
% 967	0	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with size with location with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and ion with beam same (cross\$3 with section or cross-section)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S68	27	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with (size or location) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and focus\$3 with ion with beam	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11

S69	5	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with (size or location) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and focus\$3 with ion with beam same (cross \$3 with section or cross-section)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	13:38
S70	. 2	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root and (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with (size or location) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and scan\$4 with auger with microscopy	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S71	3	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root and scan \$4 with auger with microscopy	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 13:50

S72	2	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root with (semiconductor or chip or wafer or IC or integrated adj circuit) and scan\$4 with auger with microscopy	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S73	2	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root same (semiconductor or chip or wafer or IC or integrated adj circuit) and scan\$4 with auger with microscopy	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S74	6	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root same (semiconductor or chip or wafer or IC or integrated adj circuit) and (auger with electron with spectroscopy or scan\$4 with auger with microscopy)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S75	58	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (semiconductor or chip or wafer or IC or integrated adj circuit) and (auger with electron with spectroscopy or scan\$4 with auger with microscopy) and focus \$3 with ion with beam	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11

S76	8	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (semiconductor or chip or wafer or IC or integrated adj circuit) and (auger with electron with spectroscopy or scan\$4 with auger with microscopy) and cut\$4 with focus\$3 with ion with beam	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S77	2	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (semiconductor or chip or wafer or IC or integrated adj circuit) and (auger with electron with spectroscopy or scan\$4 with auger with microscopy) and cut\$4 with focus\$3 with ion with beam same (cross \$3 with section or cross-section)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OZ	2008/06/11
S78	3	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (semiconductor or chip or wafer or IC or integrated adj circuit) and (auger with electron with spectroscopy or scan\$4 with auger with microscopy or energy with dispersive with spectrometer) and cut \$4 with focus\$3 with ion with beam same (cross\$3 with section or cross-section)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11

S79	34	\$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S80	12	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with process	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	8	14:22

S81	9	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	O X	2008/06/11
S82	14	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with type	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	WOR	00 00	2008/06/11

S84			US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	NON CONTROL OF THE PROPERTY OF	2008/06/11 14:31
S85	6	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with type not \$82	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 14:32

S86	2312	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with type not \$82	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 14:33
S 87	1544	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with type not \$82	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	N COOK	2008/06/11 14:34
S88	1332	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction\$2 or error	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	N	2008/06/11

		or problem or disorder or abnormal\$5) with type				
S89	24	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root same (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with type not \$82	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S92	38	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root same (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with type	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S93	333	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root same (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified) with (defect	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11

		or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with type		***************************************	· · · · · · · · · · · · · · · · · · ·	
S94	15	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (class or classification or categor \$6 or classify\$3 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with type	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OZ	2008/06/11 15:26
S95	123	"5991699".uref.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:29
S96	26	"5991699".uref. and (class or classification or categor\$6 or classify \$3 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with type	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:29

S97	0	"5991699".uref. and (class or classification or categor\$6 or classify \$3 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with type and (point with scan or delayer or depth with profile) with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:34
S98	1	(class or classification or categor\$6 or classify \$3 or classified or table) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with type same (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (point with scan or delayer or depth with profile) with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:35
S99	51	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with type same (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (point with scan or delayer or depth with profile) with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:36
S100	17	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (point with scan or delayer or depth with profile) with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:37

S101	1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (point adj scan or delayer or depth adj profile) same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:39
S102	55	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (point adj scan or delayer or depth adj profile) same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:43
S103	82	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (point adj scan or delayer or depth adj profile) same chemical	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:43
S104	1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and point adj scan with delayer with depth adj profile same chemical	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:44

S105	1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and point adj scan with delayer with depth adj profile same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:45
S106	1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) same (die or semiconductor or wafer or chip or IC or integrated adj circuit) and point adj scan with delayer with depth adj profile same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:46
S107	1	point adj scan with delayer with depth adj profile same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:46
S109	2	point adj scan same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:47
S110	1	delayer same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:47
S111	128	depth with profile same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:47
S112	49	depth with profile with chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:48

S113	1	depth with profile with chemical with analysis with (die or semiconductor or wafer or chip or IC or integrated adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:48
S114	0	point with scan\$4 with chemical with analysis with (die or semiconductor or wafer or chip or IC or integrated adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:50
S115	0	point with scan\$4 with chemical with analysis same (die or semiconductor or wafer or chip or IC or integrated adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:51
S116	7	point with scan\$4 with chemical with analysis and (die or semiconductor or wafer or chip or IC or integrated adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:51
S117	1	point adj scan with delayer with depth adj profile	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:56
S118	2	point adj scan with depth adj profile	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 15:56
S119	751	point with scan\$4 with analysis and (die or semiconductor or wafer or chip or IC or integrated adj circuit)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:03
S120	4	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root same (die or semiconductor or wafer or chip or IC or integrated adj circuit) and point with scan\$4 with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:03

S121	2	("6734427").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/11 16:07
S122	3	energy with dispers\$4 with spectometer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:11
S123	1163	energy with dispers\$4 with spectrometer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:11
S124	1	energy with dispers\$4 with spectrometer with thick with particle	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:12
S125	1	energy with dispers\$4 with spectrometer same thick with particle	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:12
S127	0	energy with dispers\$4 with spectrometer with size same (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:13
S128	19		US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:14
S129	64	(EDS or energy with dispers\$4 with spectrometer) with (analyz\$3 or analys\$3) with microscop\$4 with particle	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:20
S130	1	energy with dispers\$4 with spectrometer with thick with particle and cut\$4 with (FIB or focus with ion wiht beam) with (cross- section or cross\$3 wiht section)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:21

S131	1	thick with particle and (FIB or focus with ion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:22
S132	7	(EDS or energy with dispers\$4 with spectrometer) with (analyz\$3 or analys\$3) with microscop\$4 with particle and auger with (analys\$3 or analyz\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 16:23
S133	3	(("6744266") or ("5985680") or ("5991699")).PN.	USPAT	OR	OFF	2008/06/11 16:28
S134	5	(("6744266") or ("6734277") or ("5985680") or ("5991699") or ("5561293")).PN.	USPAT	OR	OFF	2008/06/11 16:30
S135	28	(US-20050049836-\$ or US-20080129988-\$ or US-20080115029-\$ or US-20080081385-\$ or US-20050004774-\$ or US-20020196969-\$ or US-20040252879-\$ or US-20050159909-\$ or US-20050177264-\$ or US-20050080572-\$ or US-20040122859-\$). did. or (US-6516433-\$ or US-7337034-\$ or US-6407386-\$ or US-6407386-\$ or US-6392434-\$ or US-6392434-\$ or US-677677-\$ or US-5985680-\$ or US-5991699-\$ or US-7020536-\$ or US-7071011-\$ or US-7359544-\$ or US-6744266-\$ or US-6734277-\$ or US-5561293-\$). did. or (US-6516433-B-\$ or US-5972728-\$). did.	US-PGPUB; USPAT; DERWENT	OR	S	2008/06/11

S136	5	(("6744266") or ("6734477") or ("5985680") or ("5991699") or ("5561293")).PN.	USPAT	OR	OFF	2008/06/11 17:34
S137	5	(("6744266") or ("6734427") or ("5985680") or ("5991699") or ("5561293")).PN.	USPAT	OR	OFF	2008/06/11 17:34
S138	0	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with root with (die or semiconductor or wafer or chip) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with underlayer with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR		17:58 17:58
S139	2	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root with (die or semiconductor or wafer or chip) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with underlayer with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR		2008/06/11 17:58

S140	2	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root with (die or semiconductor or wafer or chip) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with underlayer same (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S141	1	\$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S142	3	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with root with (die or semiconductor or wafer or chip) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with underlayer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11

S143	68	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3) with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with underlayer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:01
S144	24	locat\$3 with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with underlayer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:01
S145	13	locat\$3 with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with underlayer with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:02
S146	23	type with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with underlayer same (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:04
S147	18	type with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with underlayer with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:05
S148	18	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with type with underlayer with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:05

S149	8	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with underlayer with (site or position or location) with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:07
S150	8	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with underlayer with (site or position or location) same (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:08
S151	19	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with underlayer with (site or position or locat\$3) same (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:09
S152	19	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with underlayer with (site or position or locat\$3) with (die or semiconductor or wafer or chip)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:09
S153	17	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur \$6) with (defect or fail \$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal \$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and underlayer with	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:11

		(site or position or locat \$3) with (die or semiconductor or wafer or chip)				
S154	18	\$3 or indicat\$3 or detect\$3 or identif\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11
S155	18	\$3 or indicat\$3 or detect\$3 or identif\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	MOR	ON	2008/06/11 18:13
S156			US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:19

S157	6	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur\$6 or inspect\$4) with cause with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (under-layer or low \$3 adj layer or underlayer) not \$155	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR		2008/06/11
S158	0	(determin\$3 or monitor \$3 or indicat\$3 or detect\$3 or identif\$4 or sens\$3 or measur\$6 or inspect\$4) with cause with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (under-layer or underlayer) not \$155	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:22
\$159	112	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (underlayer or underlayer) not \$155	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:24

S160	10	cause with (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (under-layer or underlayer) not \$155	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/11 18:24
S161	1	point adj scan with depth adj profile same chemical with analysis	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 13:29
S162	224	702/59.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 13:48
S163	528	702/65.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 14:14
S164	789	702/185.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 14:15
S165	555	702/181.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 14:15
S166	380	702/155.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:17
S167	514	702/81.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:18
S168	527	702/84.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:18

S170	956	714/736.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:18
S171	100	714/737.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:19
S172	306	714/732.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:19
S173	3848	714/724.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:19
S174	1284	714/763.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:19
S175	1668	714/726.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:20
S176	580	714/727.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:20
S177	161	714/728.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:26
S178	956	714/736.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:26
S179	100	714/737.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:26

S180	1539	714/738.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:26
S181	3492	714/718.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:26
S182	423	714/723.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:30
S183	1875	257/e21.525.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:30
S184	1757	257/751.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:47
S185	556	257/752.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:47
S186	3202	257/774.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:47
S187	1140	324/763.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:48
S188	5689	324/765.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:48
S189	2137	700/121.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:53

S190	454	700/109.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:53
S191	619	700/110.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:56
S192	723	700/95.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:56
S193	1195	700/117.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:56
S194	2137	700/121.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:58
S195	2739	438/14.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 17:58
S196	759	382/149.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 18:00
S197	4124	365/201.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 18:00
S198	1	scan with analy\$4 same delayer with analy \$4 same depth with profile with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 18:04
S199	1	scan with analy\$4 same delayer with analy \$4 and depth with profile with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 18:05

S200	1	scan with analy\$4 and delayer with analy\$4 and depth with profile with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 18:05
S201	3	scan with analy\$4 and delay\$3 with analy\$4 and depth with profile with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 18:05
S202	1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (point with scan or delayer or depth with profile) with analysis and chemical\$2 with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15
S203	34	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (scan or delay\$3 or depth with profile) with analy\$4 and chemical\$2 with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15
S204	25	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (scan or delay\$3 or depth with profile) with analy\$4 same chemical\$2 with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15

\$205	6	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (scan or delay\$3 or depth with profile) with analy\$4 with chemical\$2 with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15
S206	1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and chemical\$2 with analy\$4 with "0.2"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 20:29
S207	5	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and chemical\$2 with analy\$4 with "0.2"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/15 20:30
S208	2	("5847821").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/15 20:34
S209	8	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and locat\$3 with (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16

		or abnormal\$5) with (under-layer or underlayeror or under adj layer or lower-layer or lowerlayer or lower adj layer)		and the second s		ammammamma
S211	31	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (under-layer or underlayer or underlayer or lower-layer or lowerlayer or lower adj layer) with (locat\$3 or position or site or area)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16
S212	15	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (under-layer or underlayer or underlayer or lower-layer or lowerlayer or lower adj layer or lower-layer or lowerlayer) with (locat\$3 or position or site or area) and (classify\$4 or classification or class or categor\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16

S213	12	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (under-layer or under1 adj layer or lower-layer or lowerlayer or lower adj layer) with (locat\$3 or position or site or area) and (classify\$4 or classification or class or categor\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 09:55
S214	15	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (under-layer or underlayeror or under adj1 layer or lower-layer or lowerlayer or lower adj layer) with (locat\$3 or position or site or area) and (classify\$4 or classification or class or categor\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 09:55

S215	0	(defect or fail\$3 or	US-PGPUB;	OR	ON	2008/06/16
		fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with located with (underlayer or under adj1 layer or lower-layer or lower adj layer)	USPAT; EPO; JPO; DERWENT; IBM_TDB			10:13
S216	14	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with located with (under-layer or underlayeror or under adj1 layer or lower-layer or lower adj layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16
S217	· 1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with located with (under-layer or underlayeror or under adj1 layer)	US-PGPUB; US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16

S218	2	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (posit\$4 or locat\$4) with (underlayer or underlayer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OO C	2008/06/16 10:29
S219	31	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (underlayer or underlayer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OZ	2008/06/16 10:30
\$220	158	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (underlayer or under adj1 layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	MOD S	2008/06/16 10:34
S221	26	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (underlayer or underlayer or under adj1 layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 10:34

S222	9	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (under-layer or under adj layer) with (locat\$3 or position or site or area)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	No.	2008/06/16 10:48
S223		(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (under-layer or under adj layer) with (locat\$3 or position or site or area) and chemical\$2 with analy\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR		2008/06/16 10:57
S224	1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with (under-layer or underlayer or under adj layer) with (locat\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	N N N N N N N N N N N N N N N N N N N	2008/06/16 10:58

		or position or site or area) and chemical\$2 with analy\$4			· mummumm.	
\$225	6	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with (under-layer or underlayer or under adj layer) with (locat\$3 or position or site or area) and (FIB or SAM or AES or EDS)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16
S226	0	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (underlayer or under adj layer) with (locat\$3 or position or site or area) and (FIB or SAM or AES or EDS) and (classify\$4 or classification or class or categor\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 11:05
S227	O	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (underlayer or under adj layer) and (FIB or SAM or AES or EDS) and (classify\$4 or classification or class or categor\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 11:06

\$228	7	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (underlayer or under adj layer) and (classify\$4 or classification or class or categor\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 11:06
\$229	1	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (energy dispersive spectrometer or EDS) with ("0.1" or "0.2" or "0.3") and (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (under-layer or underlayer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16
\$230	312	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (energy dispersive spectrometer or EDS) with ("0.1" or "0.2" or "0.3")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 11:21

S231	3	(defect or fail\$3 or fault or anomaly or	US-PGPUB; USPAT; EPO;	OR	ON	2008/06/16 11:22
		malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (energy dispersive spectrometer or EDS) with ("0.1" or "0.2" or "0.3") and (defect or fail\$3 or fault or anomaly or malfunction \$2 or error or problem or disorder or abnormal \$5) with (under-layer or underlayer or underlayer)	JPO; DERWENT; IBM_TDB			
S232		(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with (under-layer or underlayer)	US-PGPUB; US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	, (ON	2008/06/16
\$233	14	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) near (under-layer or underlayer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16

\$234	16	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5 or loss) near (under-layer or underlayer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16
\$235	2	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5 or loss) near (under-layer or underlayer) not \$233	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16
S236	159	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5 or loss) with (die or semiconductor or wafer or chip or IC or integrated adj circuit) with (under-layer or underlayer or under adj layer) not \$233	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 13:16

S237	22	\$3 or indicat\$3 or detect\$3 or identif\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 13:17
S238	39	(defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5) with cause with (die or semiconductor or wafer or chip or IC or integrated adj circuit) and (defect or fail\$3 or fault or anomaly or malfunction\$2 or error or problem or disorder or abnormal\$5 or loss) with (under-layer or underlayer) not \$233	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/06/16 13:23

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